## NSN 5961-00-532-1032

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-532-1032 **Inclosure Material:** Metal **Overall Length:** 1.675 inches **Overall Diameter:** 1.063 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.031 inches and 1.063 inches **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 3000.00 amperes zero-gate-voltage source current any acceptable **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug **Specification Data:** 80131-release4936 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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